



UNIVERSITÀ
DEGLI STUDI DI MILANO-BICOCCA

COURSE SYLLABUS

Physical Chemistry of Solid State and Surfaces

1920-1-F5302Q011

Aims

Relating fundamental concepts of the solid state and surface physical chemistry with applicative issues in the science and technology of semiconductors.

Knowledge and understanding

At the end of the course the student knows:

- The main characterization techniques for material and surface properties
- the main growth processes for semiconductor (bulk material and thin films)
- the role of defects on material properties with a focus on semiconductors

Applying knowledge and understanding

At the end of the course the student is able to:

- apply a method to understand and to predict the role of defects on material properties based on the chemical physics concept of solid solution
- analyse the results of surface and material characterization carried out with several characterization techniques such as SEM, EDX, XPS, SIMS

- know that any growth techniques could introduces defects which can modified the material properties and the device related performances

-recognise the role and the importance of the defects in material science

Making judgements

At the end of the course the student is able to:

- choose the best growth method and characterization techniques to be used according to the properties and functionality of the material he/she wants to have or to investigate

- avoid any contamination sources or to control them

Communication skills

The student will be able to describe and to explain orally with a suitable language the subjects of the class and to sustain a contradictory on the basis of judgment abilities developed autonomously on class [topics](#)

Learning skills

The student will be able to apply the acquired knowledge to contexts different from those presented during the course, and to understand the topics covered in the scientific literature concerning the defectivity in the materials, as well as the complex relationship among the growth processes and the material properties.

Contents

Importance of defects on material properties, mainly in semiconductors. Elements of physical chemistry of surfaces. Adsorption phenomena: physisorption and chemisorption. Principal methods and techniques of Surface Characterization. Growth techniques of massive materials and thin film deposition procedures. Correlation of properties, defects and growth techniques

Detailed program

Defects in solids : Point and extended defects (dislocations, grain boundaries, antiphase domains, stacking fault) and their interactions. Elements of surface crystallography. Surface relaxation and reconstruction in vacuum. Surfaces of solids: estimate of surface energies and free energies. Adsorption phenomena: Langmuir adsorption isotherm, thermodynamics of adsorption. Physisorption: models, rates Chemisorption: molecular view, isotherms, kinetics. Principal methods and techniques of Surface Characterization and defectivity characterization (SEM XPS, AUGER, SIMS, DLTS , BET methods). Growth techniques of massive materials . General aspects of thin film deposition procedures and main thin film deposition techniques and relationships with material defectuality. Several case studies will be discussed for each topic

Prerequisites

Main Physical Chemistry I and Materials Science topics in 1st cycle bachelor's degree programs

Teaching form

Standard lessons supplemented by supporting multimedia tools functional to a better understanding of the practical aspects

Textbook and teaching resource

S. Eliot The Physics and Chemistry of solids Wiley

J. D. Plummer , M.D. Deal, P.B. Griffin Silicon VLSI Technology Prentice Hall

J. B. Hudson Surface science an introduction

A. W. [Adamson, A.P. Gast Physical Chemistry of Surfaces 6th ed. Wiley](#)

All these books should be available in the UNIMIB library

Semester

First year, Second (spring) semester

Assessment method

The teacher assesses if and to what extent the student has reached the course objectives.

A formal knowledge-based evaluation of the general topics delivered. The examination is performed through an oral exam .

The students can do a mid term test: a class presentation of about 15 minutes on a topic selected by the students from a list that the teacher will give at about the end of March of each year. This presentation will count for 30 % of your final grade

Office hours

All days from Monday to Friday upon e-mail request
